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### Vishay Semiconductors

# 650 V Power SiC Merged PIN Schottky Diode, 10 A



#### LINKS TO ADDITIONAL RESOURCES







PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	10 A			
$V_{R}$	650 V			
V <sub>F</sub> at I <sub>F</sub> at 150 °C	1.75 V			
T <sub>J</sub> max.	175 °C			
I <sub>R</sub> at V <sub>R</sub> at 175 °C	5 μΑ			
Q <sub>C</sub> (V <sub>R</sub> = 400 V)	28 nC			
Package	2L TO-220AC			
Circuit configuration	Single			

#### **FEATURES**

 Majority carrier diode using Schottky technology on SiC wide band gap material



Positive V<sub>F</sub> temperature coefficient for easy paralleling

- · Virtually no recovery tail and no switching losses
- Temperature invariant switching behavior
- 175 °C maximum operating junction temperature
- MPS structure for high ruggedness to forward current surge events
- Meets JESD 201 class 1A whisker test
- Solder bath temperature 275 °C maximum, 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters.

#### **MECHANICAL DATA**

Case: 2L TO-220AC

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

Mounting torque: 10 in-lbs maximum

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	$V_{RRM}$		650	V	
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 125 °C (DC)	10	Α	
DC blocking voltage	$V_{DC}$		650	V	
Repetitive peak surge current	I <sub>FRM</sub>	$T_C$ = 25 °C, f = 50 Hz, square wave, DC = 25 %	35	Α	
Non-repetitive peak forward surge current	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 10$ ms, half sine wave	68	^	
		$T_C = 110$ °C, $t_p = 10$ ms, half sine wave	60	Α	
Power dissipation	P <sub>tot</sub> (1)	T <sub>C</sub> = 25 °C	60	W	
		T <sub>C</sub> = 110 °C	26		
I <sup>2</sup> t value	∫i <sup>2</sup> dt	T <sub>C</sub> = 25 °C	23	A <sup>2</sup> s	
		T <sub>C</sub> = 110 °C	18		
Operating junction and storage temperatures	T <sub>J</sub> <sup>(2)</sup> , T <sub>Stg</sub>		-55 to +175	°C	

#### **Notes**

<sup>(1)</sup> Based on maximum R<sub>th</sub>

 $<sup>^{(2)}</sup>$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 



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<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
		I <sub>F</sub> = 10 A	-	1.50	1.80	
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 A, T <sub>J</sub> = 150 °C	-	1.75	1.95	V
		I <sub>F</sub> = 10 A, T <sub>J</sub> = 175 °C	-	1.85	-	
Reverse leakage current	I <sub>R</sub>	$V_R = V_R$ rated	-	-	55	μΑ
		V <sub>R</sub> = V <sub>R</sub> rated, T <sub>J</sub> = 150 °C	-	-	125	
		V <sub>R</sub> = V <sub>R</sub> rated, T <sub>J</sub> = 175 °C	-	5	ı	
Total capacitance	С	V <sub>R</sub> = 1 V, f = 1 MHz	-	430	ı	pF
		V <sub>R</sub> = 400 V, f = 1 MHz	-	45	-	PΓ
Total capacitive charge	Q <sub>C</sub>	V <sub>R</sub> = 400 V, f = 1 MHz	-	28	-	nC

THERMAL - MECHANICAL SPECIFICATIONS (T <sub>A</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	1.8	2.5	°C/W
Marking device				C10E	T07T	

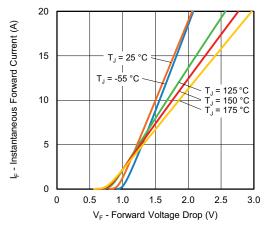


Fig. 1 - Typical Forward Voltage Drop Characteristics

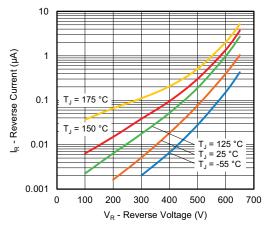


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

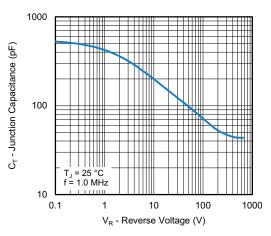


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

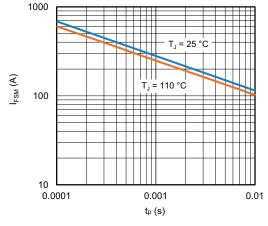


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration (Square Wave)

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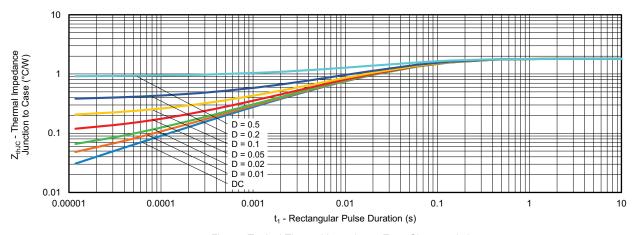


Fig. 5 - Typical Thermal Impedance Z<sub>thJC</sub> Characteristics

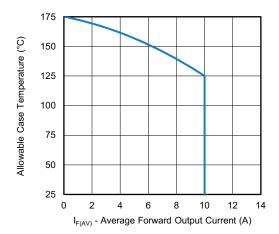


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

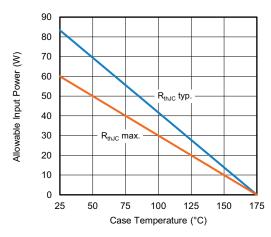


Fig. 7 - Forward Power Loss Characteristics

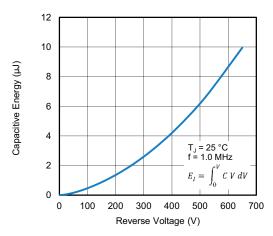


Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage

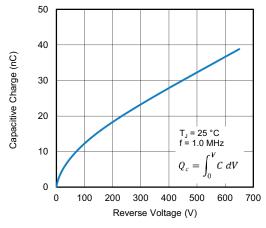


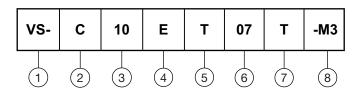
Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage



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### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

**2** - C = SiC diode

3 - Current rating (10 = 10 A)

- E = single diode

5 - Package TO-220

6 - Voltage rating: (07 = 650 V)

**7** - T = true 2 pin

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION						
PREFERRED P/N	BASE QUANTITY	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-C10ET07T-M3	50/tube	1000	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96069</u>				
Part marking information	www.vishay.com/doc?95391			
SPICE model	www.vishay.com/doc?96832			



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